

SILICON BRIDGE RECTIFIERS	REVERSE VOLTAGE - 50 to 1000Volts FORWARD CURRENT - 4.0 Amperes
FEATURES <ul style="list-style-type: none"> ● Surge overload rating -150 amperes peak ● Ideal for printed circuit board ● Reliable low cost construction utilizing molded plastic technique ● Plastic material has U/L flammability classification 94V-0 ● Mounting position: Any 	<p style="text-align: center;">Dimensions in inches and (millimeters)</p>

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave, 60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	GBU 4005C	GBU 401C	GBU 402C	GBU 404C	GBU 406C	GBU 408C	GBU 410C	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	v
Maximum RMS Voltage	V _{RMS}	30	70	140	280	420	560	700	v
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	v
Maximum Average Forward Rectified Current @ T _C =100°C (without heatsink)	I _(AV)					4.0			A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC Method)	I _{FSM}					150			A
Maximum Forward Voltage at 4.0A DC	V _F					1.0			V
Maximum DC Reverse Current at Rated DC Blocking Voltage @ T _J =25°C @ T _J =125°C	I _R					10.0			uA
I ² t Rating for Fusing (t<8.3ms)	I ² t					93			A ² s
Typical Junction Capacitance Per Element (Note1)	C _J					45			pF
Typical Thermal Resistance (Note2)	R _{θJC}					2.2			°C/W
Operating Temperature Range	T _J					-55 to +125			°C
Storage Temperature Range	T _{STG}					-55 to +150			°C

NOTES: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 2. Device mounted on 50mm*50mm*1.6mm cu plate heatsink.

FIG.1-FORWARD CURRENT DERATING CURVE

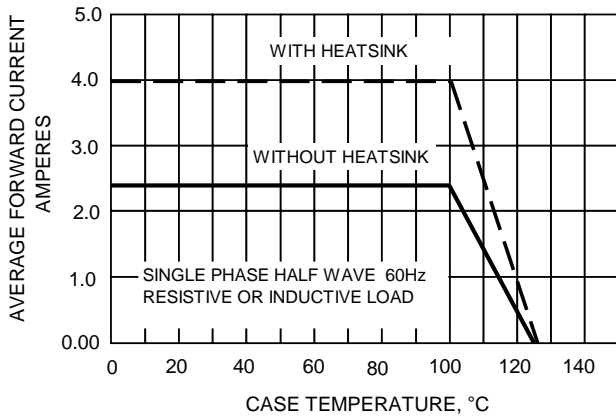


FIG.2-MAXIMUM NON-REPETITIVE SURGE CURRENT

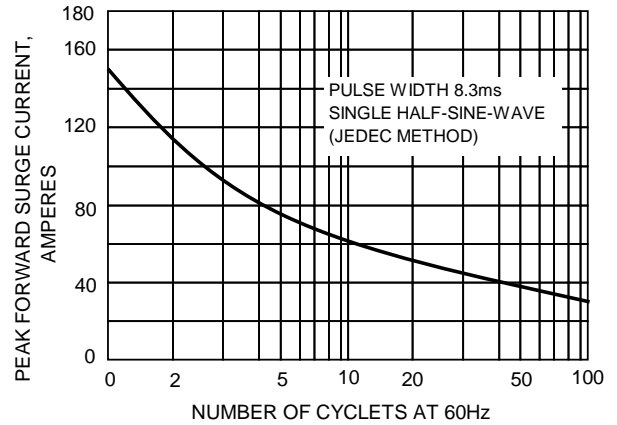


FIG.3-TYPICAL JUNCTION CAPACITANCE

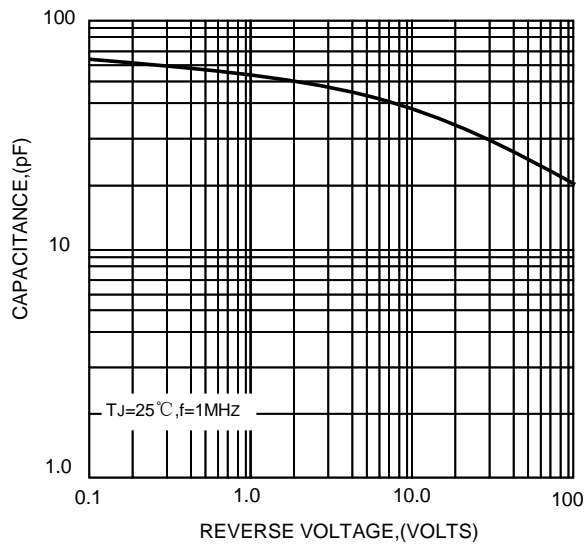


FIG.4-TYPICAL FORWARD CHARACTERISTICS

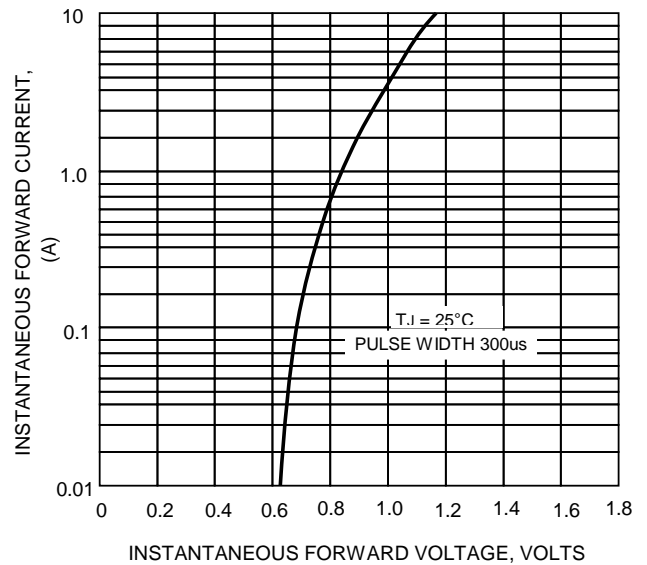


FIG.5-TYPICAL REVERSE CHARACTERISTICS

